



Preliminary Data Sheet (01-26-99)

MGAD Series

Hybrid Pulsed Laser Module

Photo of the TO-5 device

Features:

- Integral Hybrid Driver Design
- Narrow Pulse Widths: 3ns, 7ns
- Output Power Options
- QW Laser Source: 850, 905, 1550 nm

Applications:

- Range Finding
- Obstacle Avoidance
- LIDAR
- Optical Proximity Fusing
- High Speed Switching

Product Information

EG&G Canada MGAD series of hybrid pulsed laser modules incorporate the laser diode, and hybrid pulsing circuit in a compact convenient package. The series utilizes selected chip variations from our popular MOCVD grown multiple quantum well laser diode line providing narrow beam divergence and high efficiency.

The hybrid circuit includes a high speed semiconductor switching element, storage capacitor and laser diode mounted on a planar ceramic substrate. Options include single, double and triple stacked 150 μm sources producing output peak power of 24 W,

48 W and 72 W respectively.

The advantages of such a design include ease of use (the circuit requires only a single power supply and a TTL compatible trigger signal), compact size and light weight.

Operating Considerations

These modules are operated by charging the integral storage capacitor to a high voltage and discharging this stored energy through the laser diode via a high speed avalanche transistor. The transistor is triggered by a user-supplied TTL base signal.

The pulse length is predetermined at the time of manufacture and is thus not adjustable. It is recommended to use the MGAD with an external 5 KO current limiting resistor be connected between the high voltage supply and the (+HV) circuit connection. This will limit the pulse repetition rate to ~ 25 Khz. Please see Figure 3 for additional operating circuit information.

The current device design is a TO-5 sealed hybrid to protect the electronics from field environmental conditions.



MGAD Series

Maximum Ratings

Maximum ratings of voltage, current, frequency and temperature must never be exceeded. Exceeding these values can cause permanent damage to the laser diode or circuitry.

Limiting Values

High Voltage (+HV) 300V max.

Trigger Current (I_{TRIG}) 5V max.

Repetition Frequency (P_{rr})
25 KHz max.

Operating Temp. Range
-50°C* to +85°C Storage

Temp. Range
-55°C* to +100°C

Soldering (Leads Only)
5 seconds at 200°C max.

Characteristics at 25°C

Parameter	MGAD1S0607			MGAD2S0607			MGAD3S0607		
	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX
Peak Output Power, W	20	24		40	48		60	72	
High Voltage (+HV), V		280	300		280	300		280	300
Trigger Voltage, V	3.5		5.0	3.5		5.0	3.5		5.0
Trigger Pulse Width, ns	100	250	500	100	250	500	100	250	500
Optical Pulse Width, ns		7	10		7	10		7	10
Pulse Repetition Rate, kHz			25			25			25
Beam Divergence, $T \times T_{\perp}$ (deg.)	10 x 25			10 x 25			10 x 25		
Number of diode Elements	1			2			3		
Source Size, μm	1 x 150			110 x 150			220 x 150		

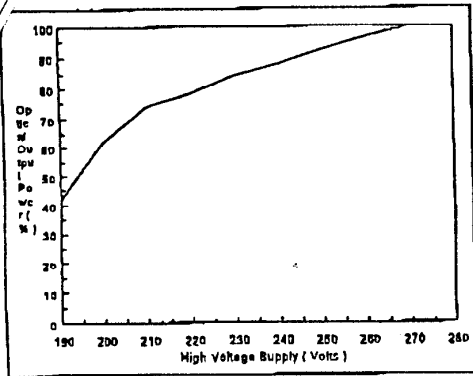


Figure 1: High Voltage Supply vs Temperature vs Relative Peak Output Power

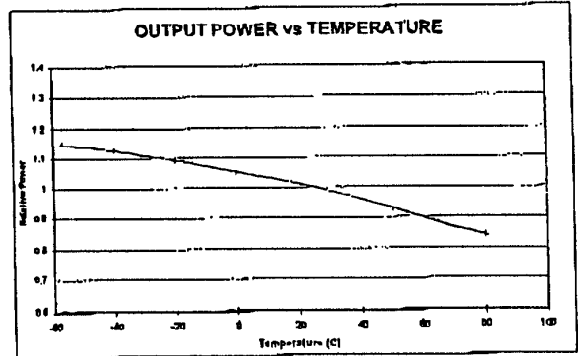
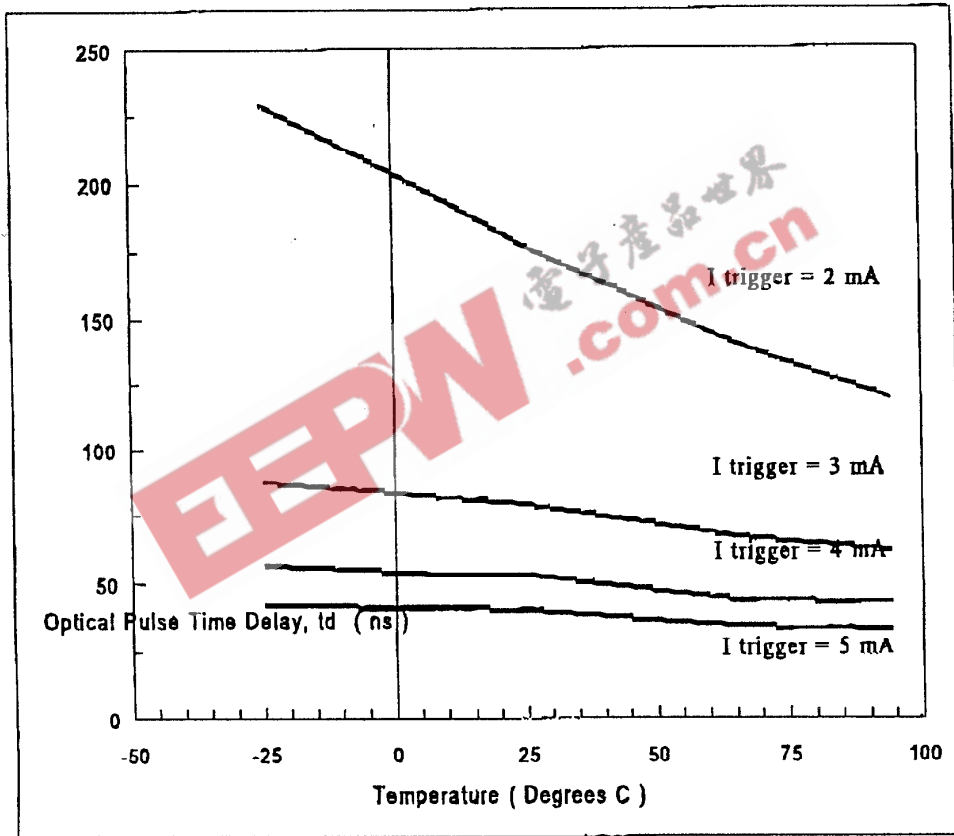


Figure 2: Peak Output Power



Note: $I_{TRIGGER} = (V_{TRIGGER} - 0.7V) / R_S$
 R_S IS THE 1kΩ resistor in Figure-4

Figure 3: Turn-on Delay.

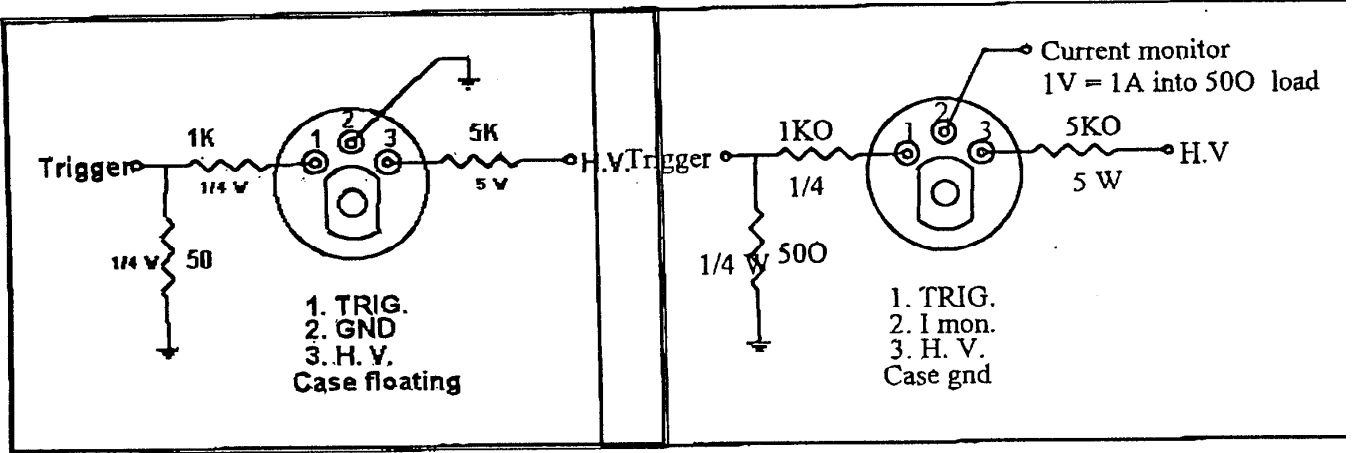


Figure 4: Recommended Interface Circuit.

ORDER PART NUMBER INFORMATION

M	X	X	D	Y	X	YY	YY	X
M	PGAZ Series							
	WAVELENGTH							
F	850nm							
G	905nm							
V	1550nm							
A	+/- 10% OF LAMBDA							
B	+/- 20%							
D	TO-5 CAN							
	# OF LASERS							
	1	1						
	2	2						
	3	3						
	4	4						
	5	5						
	ARRAY TYPE							
	L	Linear						
	S	Stack (S for 1 laser)						
	SOURCE WIDTH							
		03	3mils/75µm					
		06	6mils/150µm					
		09	9mils/225µm					
		12	12mils/300µm					
	PULSE WIDTH							
		03	3ns typical					
		07	7ns typical					
	CURRENT MONITOR							
		-	None					
		M	Monitor					

